

Surface wave supporting structures in the terahertz and optical frequency domains

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Outline



- Overview
- Background
- Theory and Methods
 - Sommerfeld Integral analysis
 - Dispersion relation
 - Surface Integral equation
- Results
 - Super-resolution Imaging
- Conclusions

Overview

- Plasmonics: subwavelength localization of electromagnetic (EM) fields
- Plasma frequency
 - Metals - Optical frequency
 - 2D Electronic Systems (2DES) - Terahertz (THz)
- Bridging the THz gap

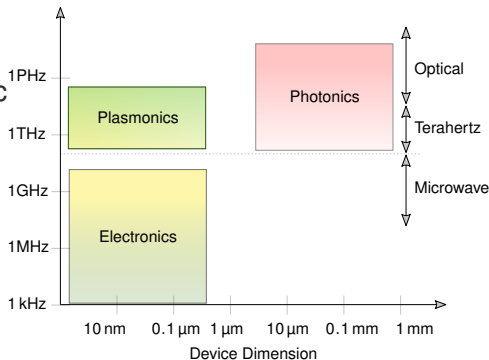


Figure: Communication Technologies at various frequencies

- Graphene
 - Grown separately, transferred to substrate
 - Currently not integrable to current electronics technology
 - Superior electronic properties
- Semiconductor heterostructures
 - Conventional epitaxial semiconductor device fabrication techniques
 - On-chip integration with silicon electronics

Background

Plasmonics Overview

- Interfacial wave phenomena
 - Metal-dielectric interface
 - Semiconductor heterostructure
- Surface plasmon polaritons (SPPs)
- Plasma frequency
 - Metals - Optical frequency
 - Semiconductors - Terahertz

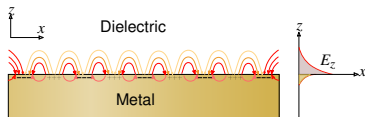


Figure: SPPs at optical frequencies

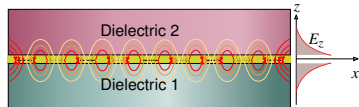


Figure: SPPs in the THz regime

Background

Surface Plasmon Polaritons

- Slow surface waves
- Reduced Wavelength
- Focusing beyond the diffraction limit

- Optical SPP

$$\text{Re} [\varepsilon_{\text{metal}}(\omega)] < 0$$

- THz SPP

$$\text{Im} [\sigma_s(\omega)] < 0$$

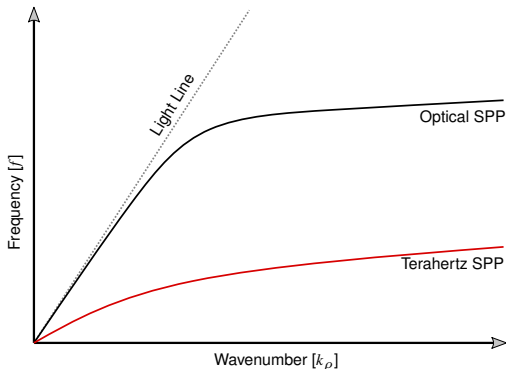


Figure: Dispersion Curve comparison

Background

Optical Nanoantennas

- Convert Localized near-field to efficient far-field radiation
- Low Q-factor
- Extremely small size
- **High Purcell Factor**

$$P = \frac{Q}{V}$$

- Directive radiation

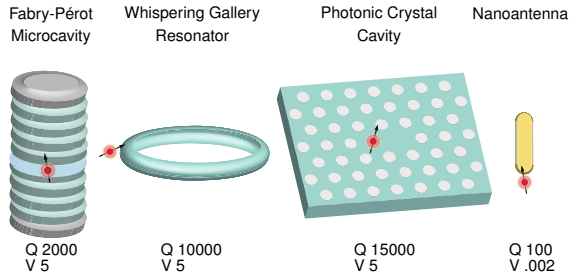
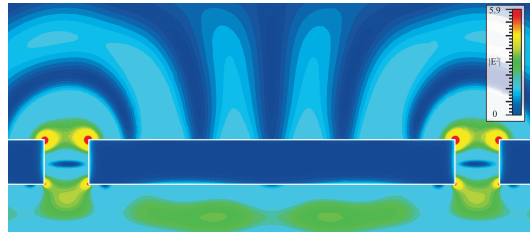
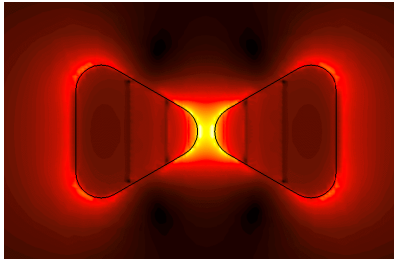
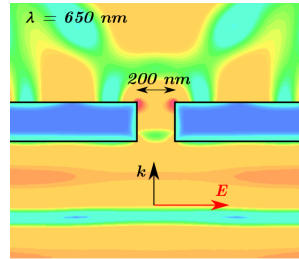


Figure: Optical resonant cavities for electric field enhancement

Background

Optical Nanoantennas (contd.)

- Scaled-down microwave antenna designs
 - Aperture antennas for subwavelength focusing
 - Broadband spectral response : Bowtie



Background

Two-dimensional Electron Gas (2DEG)

- Semiconductor Heterostructure in high electron mobility transistor (HEMT)
- High concentration of free electrons
($\sim 1 \times 10^{12} - 1 \times 10^{14} \text{ cm}^{-2}$)
- Very high Mobility
($\sim 1 \times 10^4 - 1 \times 10^6 \text{ cm}^2/\text{V/s}$)
- Formation of Quantum Well
 - Two-dimensional confinement of electrons

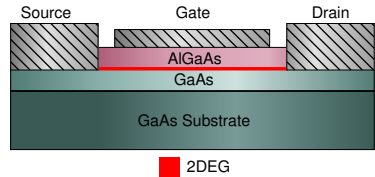


Figure: Typical GaAs/AlGaAs HEMT

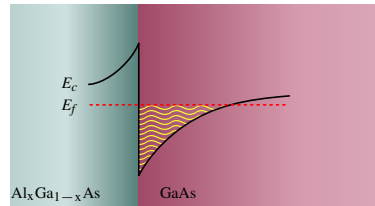
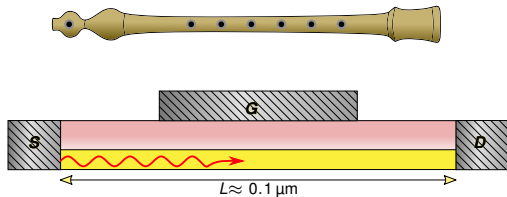


Figure: Band diagram of a GaAs/AlGaAs heterostructure

Background

2DEG (contd.)

- Plasma waves in 2DEG
- Dyakonov-Shur instability
 - Voltage bias at source and drain terminals
 - Plasma resonance
 - THz emission
- Electronic Flute
 - Tunable resonance with gate voltage
- Shallow water waves



$$\lambda = \frac{c}{f}$$

$$\Rightarrow 300 \mu\text{m}$$

Theory and Methods

2DEG Circuit model

- Drude-Lorentz Surface Conductivity

$$\sigma_s = \frac{N_s e^2}{m^*} \frac{\tau}{1 + j\tau\omega}$$

N_s - Surface charge density

τ - Scattering time

m^* - Effective electron mass

- Equivalent Circuit

$$\sigma_s = \frac{1}{Z} = \frac{1}{R + 1/j\omega C}$$

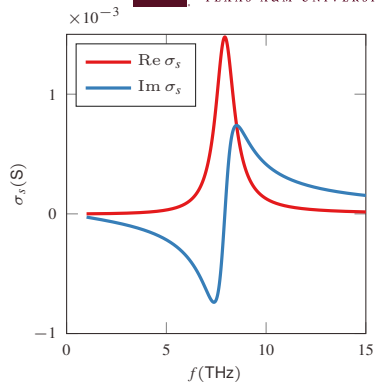
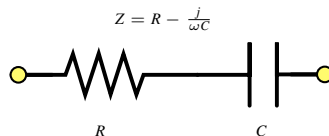


Figure: Room temperature GaN/AlGaIn 2DEG surface conductivity



Theory and Methods

Dispersion Relation for a 2D Sheet

- Conductive Sheet in freespace
- TM mode surface wave

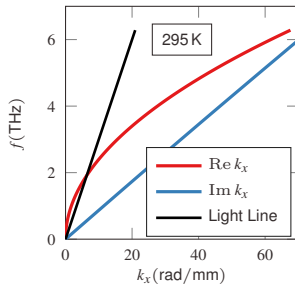
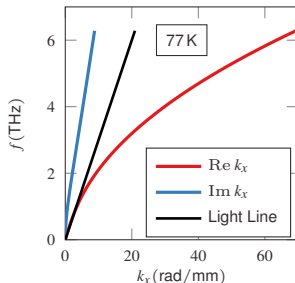
$$k_P^{TM} = \frac{\omega}{c} \sqrt{1 - \left(\frac{2}{\eta_0 \sigma_s} \right)^2}$$

- Below plasma frequency

$$\text{Im } \sigma_s < 0$$

- At low temperature

$$\text{Im } |\sigma_s| \gg \text{Re } |\sigma_s|$$



Theory and Methods

Analyzing multilayer structure

- Equivalent transmission line (TL) network
 - Dispersion relation
 - Transverse resonance condition
- $$Y^{\uparrow}(z_0) + Y^{\downarrow}(z_0) + Y_{\sigma} = 0.$$
- Below plasma frequency

